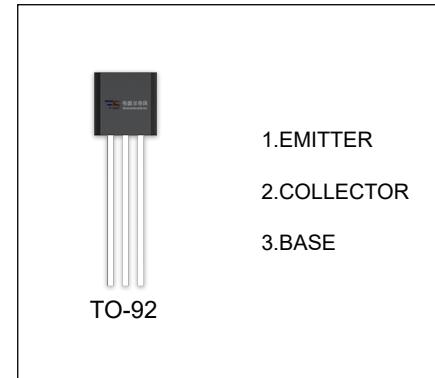


2SC388 TRANSISTOR (NPN)

FEATURES

- TV Final Pictureif Amplifier Applications



ORDERING INFORMATION

Part Number	Package	Packing Method	Pack Quantity
2SC388	TO-92	Bulk	1000pcs/Bag
2SC388-TA	TO-92	Tape	2000pcs/Box

MAXIMUM RATINGS ($T_A=25^\circ\text{C}$ unless otherwise noted)

Symbol	Parameter	Value	Unit
V_{CBO}	Collector-Emitter Voltage	30	V
V_{CEO}	Collector-Emitter Voltage	25	V
V_{EBO}	Emitter-Base Voltage	4	V
I_C	Collector Current -Continuous	50	mA
P_C	Collector Power dissipation	300	mW
T_J, T_{stg}	Operation Junction and Storage Temperature Range	-55-150	°C

T_a=25 °C unless otherwise specified

Parameter	Symbol	Test conditions	Min	Typ	Max	Unit
Collector-base breakdown voltage	V _{(BR)CBO}	I _C =10μA,I _E =0	30			V
Collector-emitter breakdown voltage	V _{(BR)CEO}	I _C =5mA,I _B =0	25			V
Emitter-base breakdown voltage	V _{(BR)EBO}	I _E =10μA,I _C =0	4			V
Collector cut-off current	I _{CBO}	V _{CB} =30V,I _E =0			0.1	μA
Emitter cut-off current	I _{EBO}	V _{EB} =3V,I _C =0			0.1	μA
DC current gain	h _{FE(1)}	V _{CE} =12.5V,I _C =12.5mA	20		200	
Collector-emitter saturation voltage	V _{CE(sat)}	I _C =15mA,I _B =1.5mA			0.2	V
Base-emitter saturation voltage	V _{BE(sat)}	I _C =15mA,I _B =1.5mA			1.2	V
Transition frequency	f _T	V _{CE} =12.5V,I _C =12.5mA	300			MHz
Collector output capacitance	C _{ob}	V _{CB} =10V,I _E =0,f=1MHz	0.8		2	pF
Power Gain	G _{pe}	V _{CC} =12.5V,I _E =-12.5mA, f=45MHZ	28		36	dB